

Power Transistor (-80V, -1A)

2SB1260 / 2SB1181

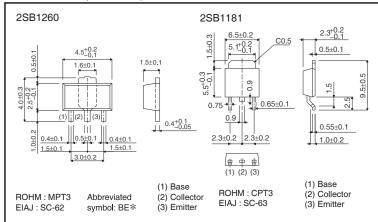
Features

- 1) Hight breakdown voltage and high current. $BV_{CEO} = -80V$, $I_C = -1A$
- 2) Good hee linearty.
- 3) Low VCE(sat).
- 4) Complements the 2SD1898 / 2SD1733.

Structure

Epitaxial planar type PNP silicon transistor

●Dimensions (Unit: mm)



* Denotes hre

●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	-80	V	
Collector-emitter voltage		VCEO	-80	V	
Emitter-base voltage		VEBO	-5	V	
Collector current		Ic	-1	A (DC)	
		ICP	-2 *1	A (Pulse)	
Collector power dissipation	2SB1260	D.	0.5		
			2 *2	W	
	2SB1181	Pc Pc	1	ı	
	2SB1181		10	W (Tc=25°C)	
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to +150	°C	

^{*1 2}SB1260 : Pw=20ms duty=1/2

●Electrical characteristics (Ta=25°C)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage		ВУсво	-80	-	_	V	Ic= -50μA
Collector-emitter breakdown voltage		BVceo	-80	-	_	V	Ic=-1mA
Emitter-base breakdown voltage		ВУево	-5	_	_	V	Iε= −50μA
Collector cutoff current		Ісво	_	_	-1	μΑ	Vcb=-60V
Emitter cutoff current		ІЕВО	_	_	-1	μΑ	V _{EB} = -4V
Collector-emitter saturation voltage		VCE(sat)	_	_	-0.4	V	Ic/I _B = -500mA/ -50mA
DC current transfer ratio		hfE	120	_	390	_	Vce=-3V, Ic=-0.1A
Transition frequency	2SB1181	f⊤	_	100	_	MHz	Vc=-10V, Ie=50mA, f=100MHz
Output capacitance	2SB1260	Cob	_	20	_	pF	V _{CB} = -10V
	2SB1181		_	25	_	pF	le=0A f=1MHz

^{*2 2}SB1260 : When mounted on a 40×40×0.7 mm ceramic board.

2SB1260 / 2SB1181 Data Sheet

●Packaging specifications and hFE

		Package	Taping	
		Code	TL	T100
Туре	hfe	Basic ordering unit (pieces)	2500	1000
2SB1260	QR		_	0
2SB1181	QR		0	_

hfe values are classified as follows:

Item	Q	R
hfe	120 to 270	180 to 390

●Electrical characteristic curves

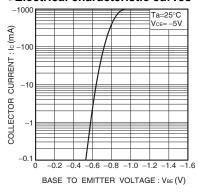


Fig.1 Grounded emitter propagation characteristics

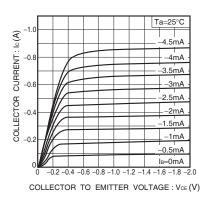


Fig.2 Grounded emitter output characteristics

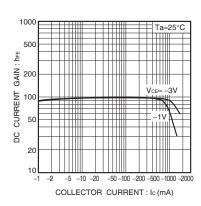


Fig.3 DC current gain vs. collector current

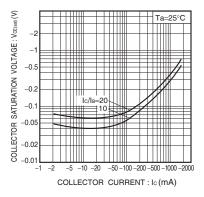


Fig.4 Collector-emitter saturation voltage vs. collector current

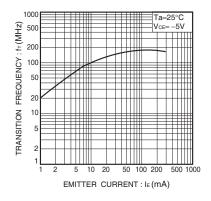


Fig.5 Gain bandwidth product vs. emitter current

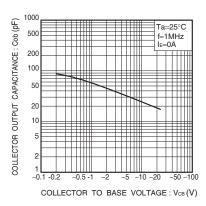


Fig.6 Collector output capacitance vs. collector-base voltage

Notes

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